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FDD1600N10ALZ N-Channel PowerTrench[®] MOSFET 100 V, 6.8 A, 160 mΩ

Features

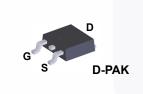
- $R_{DS(on)}$ = 124 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 3.4 A
- R_{DS(on)} = 175 mΩ (Typ.) @ V_{GS} = 5 V, I_D = 2.1 A
- Low Gate Charge (Typ.2.78 nC)
- Low C_{rss} (Typ. 2.04 pF)
- Fast Switching
- 100% Avalanche Tested
- Improved dv/dt Capability
- RoHS Compliant

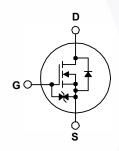
Description

This N-Channel MOSFET is produced using Fairchld Semiconductor's advanced PowerTrench[®] process that has been tailored to minimize the on-state resistance and maintain superior switching performance.

Application

- Consumer Appliances
- LED TV and Monitor
- Synchronous Rectification
- Uninterruptible Power Supply
- Micro Solar Inverter





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

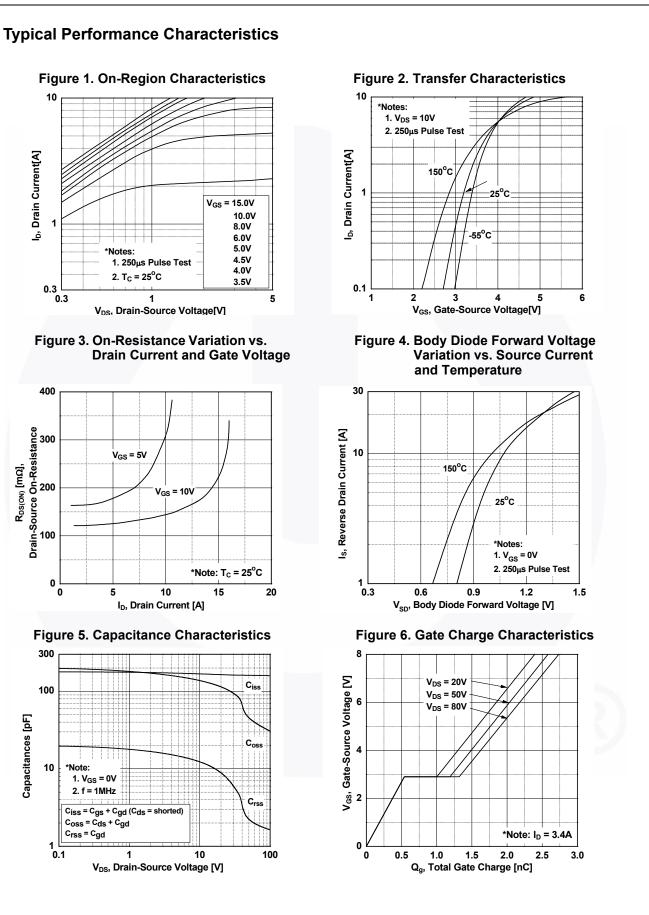
Symbol		FDD1600N10ALZ	Unit			
V _{DSS}	Drain to Source Voltage	100	V			
V _{GSS}	Gate to Source Voltage			±20	V	
ID	Drain Current	- Continuous (T _C = 25 ^o C)		6.8	Α	
	Drain Current	- Continuous (T _C = 100 ^o C)		4.3		
I _{DM}	Drain Current	- Pulsed	(Note 1)	13.6	А	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		(Note 2)	5.08	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		6.0	V/ns		
P _D	Dower Dissinction	(T _C = 25°C)		14.9	W	
	Power Dissipation	- Derate Above 25°C		0.12	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C		
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		Seconds	300	°C	

Thermal Characteristics

Symbol	Parameter	FDD1600N10ALZ	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	8.4	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max.	87	0/00

January 2014

		Packag	ge Packing Method Reel Size		Reel Size	Тар	e Width	Qua	ntity	
		DPAK	Tape ar	nd Reel	330 mm	1	6 mm	2500 units		
Electrica	l Chara	cteristics T _c =2	25ºC unless	otherwise note	ed.					
Symbol	ç			Test Conditions			Min.	Тур.	Max.	Unit
Off Charac	teristics	i								
BV _{DSS}	Drain to \$	Source Breakdown Vo	Itage	I _D = 250 μA, V _{GS} = 0 V			100	-	-	V
∆BV _{DSS}		Breakdown Voltage Temperature		$I_D = 250 \ \mu\text{A}$, Referenced to 25°C			-	0.1	-	V/ºC
$/\Delta T_J$		Coefficient		$V_{\rm DS} = 80 \text{ V}, \text{ V}_{\rm GS} = 0 \text{ V}$				_	1	
I _{DSS}	Zero Gat	Zero Gate Voltage Drain Current		$V_{DS} = 80 V, V_{GS} = 0 V$ $V_{DS} = 80 V, V_{GS} = 0 V, T_{C} = 125^{\circ}C$			-	-	500	μA
I _{GSS}	Gate to S	Gate to Source Leakage Current		V _{GS} = ±20 V			-	-	±10	μA
On Charac	teristics									
V _{GS(th)}	-	eshold Voltage		V _{GS} = V _{DS} , I	= 250 μA	\	1.4	-	2.8	V
				V _{GS} = 10 V,			-	124	160	
RDS(on)	R _{DS(on)} Static Drain to Sou		rce On Resistance		$V_{GS} = 5 V, I_D = 2.1 A$			175	375	mΩ
9 _{FS}	Forward	Transconductance		V _{DS} = 10 V, I	_D = 6.8 A		-	19.6	-	S
Dynamic C	Character	ristics								
C _{iss}		pacitance		V _{DS} = 50 V, V _{GS} = 0 V,			-	169	225	pF
C _{oss}		apacitance				-	43	55	pF	
C _{rss}	Reverse	Transfer Capacitance		f = 1 MHz		Ē		2.04	-	pF
C _{oss(er)}	Energy R	Related Output Capacit	ance	V _{DS} = 50 V, V _{GS} = 0 V			85	-	pF	
Q _{g(tot)}	Total Gat	e Charge at 10V		V _{GS} = 10 V	Vpp	, = 50 V,	-	2.78	3.61	nC
Q _{g(tot)}	Total Gat	e Charge at 5V		V_{GS} = 5 V	_{PS} = 5 V I _D = 6.8 A			1.5	1.95	nC
Q _{gs}	Gate to S	Source Gate Charge					-	0.72	-	nC
Q _{gd}	Gate to D	Drain "Miller" Charge					-	0.56	-	nC
V _{plateau}		teau Volatge		(Note 4) $V_{DS} = 0 V, I_D = 3.4 A$ $V_{DS} = 50 V, V_{GS} = 0 V$		-	4.02	-	V	
Q _{sync}		e Charge Sync.				-	2.5	-	nC	
Q _{oss}	Output C	-				-	5.2	-	nC	
ESR	Equivaler	nt Series Resistance (G-S)	f = 1 MHz			-	2.1	-	Ω
Switching	Characte	eristics								
t _{d(on)}	Turn-On Delay Time							7	24	ns
t _r	Turn-On Rise Time			$V_{DD} = 50 \text{ V}, \text{ I}_{D} = 6.8 \text{ A},$			-	2	14	ns
t _{d(off)}	Turn-Off	Delay Time		$V_{\rm GS}$ = 10 V, R _G = 4.7 Ω		2	-	13	36	ns
t _f	Turn-Off	Fall Time				(Note 4)	-	2	14	ns
Drain-Sou	rce Diod	e Characteristics	;							
I _S	Maximum Continuous Drain to Source Diod			de Forward Current			-	-	6.8	Α
I _{SM}	Maximum Pulsed Drain to Source Diode F		ce Diode Fo	orward Current			- /	-	13.6	А
V _{SD}		Drain to Source Diode Forward Voltage		V _{GS} = 0 V, I _{SD} = 6.8 A			-	-	1.3	V
t _{rr}		Recovery Time		$V_{GS} = 0 V, I_{SD} = 6.8 A, V_{DS} = 50 V,$		-	37	-	ns	
Q _{rr}	Reverse	Recovery Charge		$dI_F/dt = 100$	₩µS		-	42	-	nC



FDD1600N10ALZ — N-Channel PowerTrench[®] MOSFET

10

I_b, Drain Current[A]

1

0.3 L 0.3

400

Drain-Source On-Resistance

0

300

100

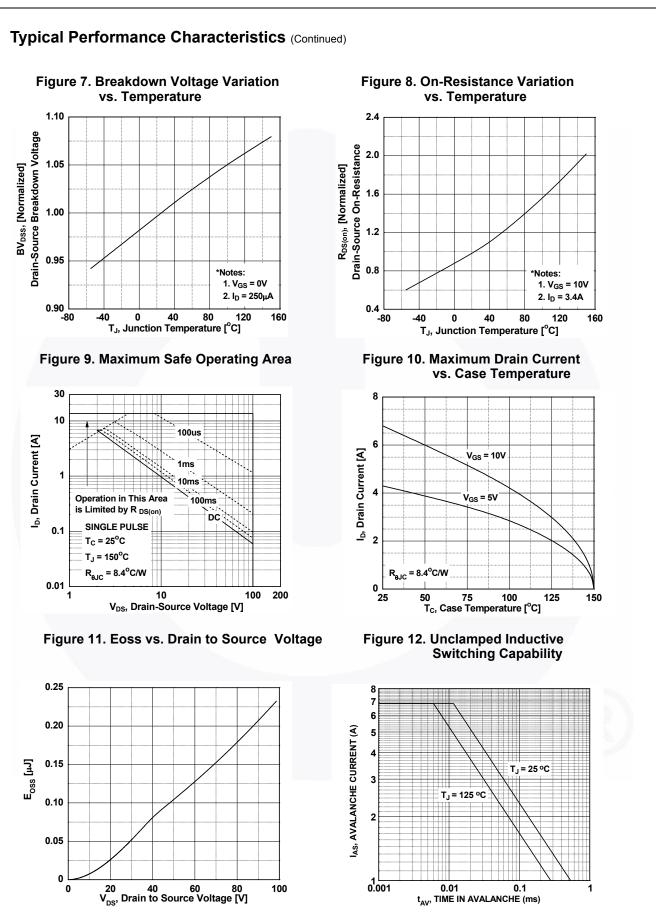
10

1 0.1

Capacitances [pF]

0

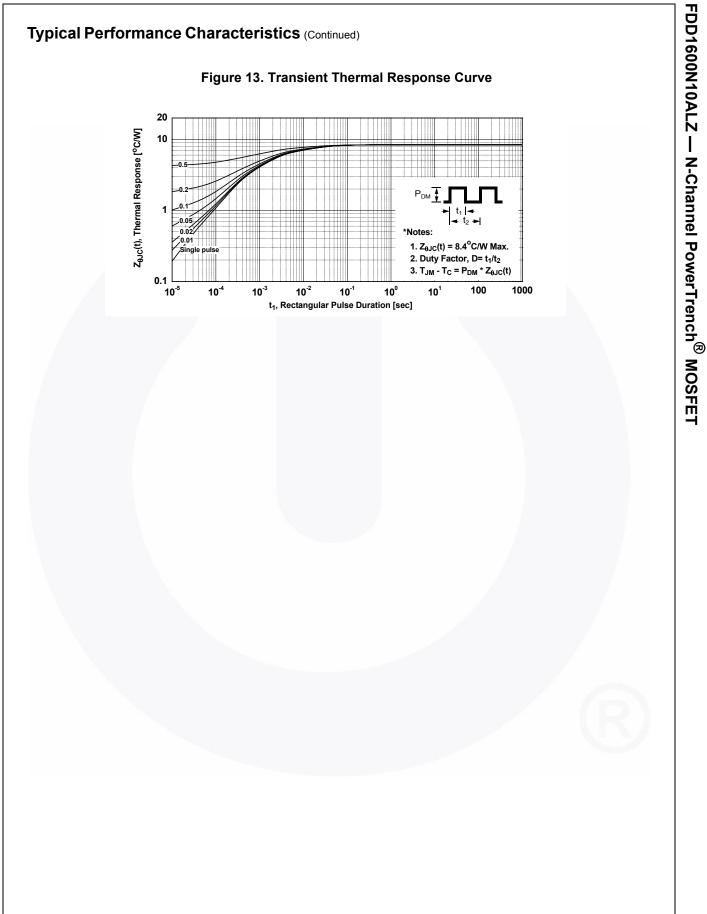
R_{DS(ON)} [mΩ],

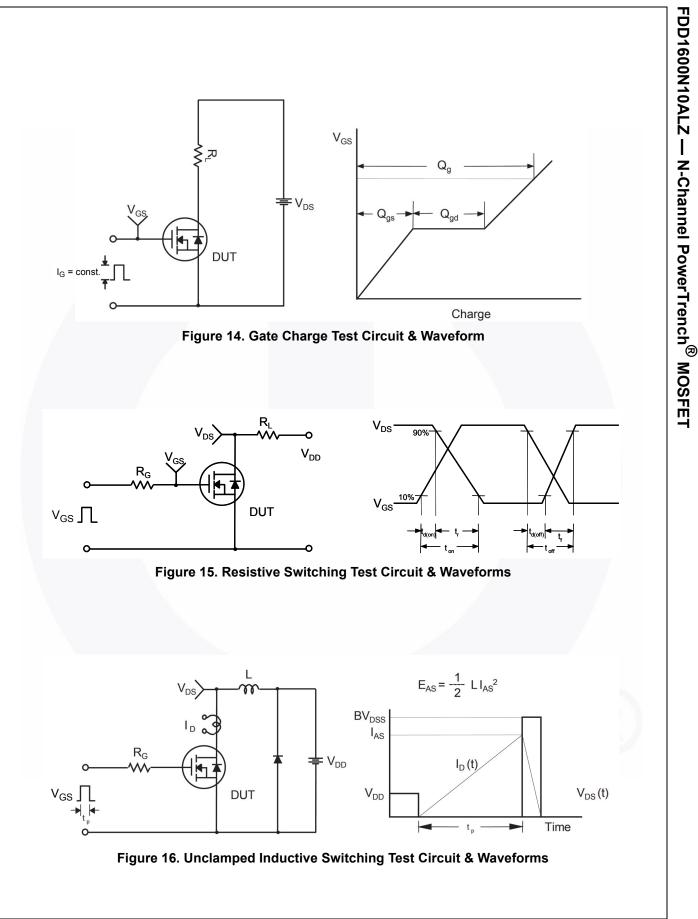


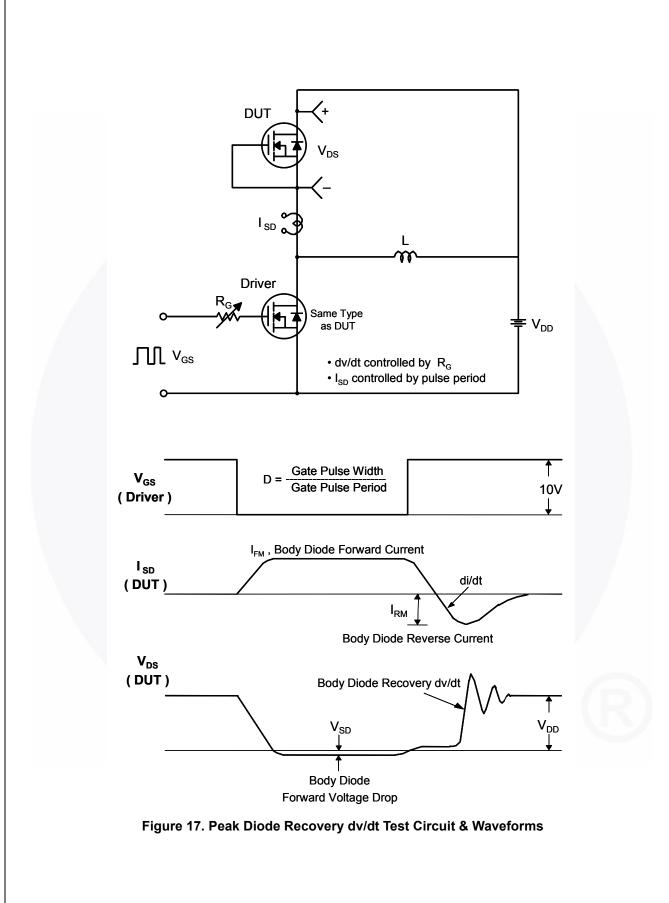
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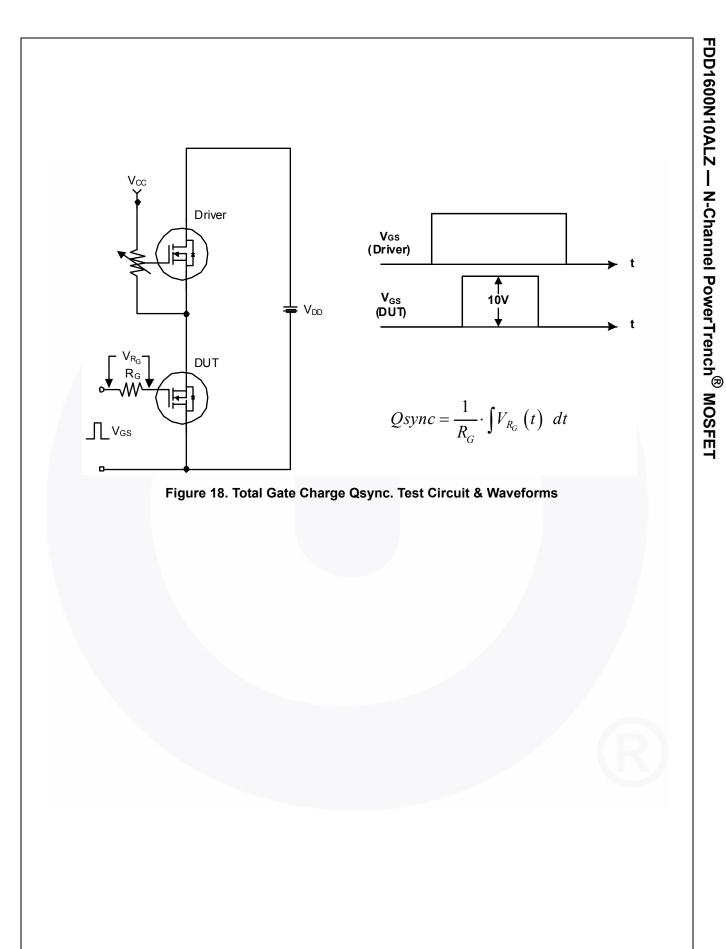
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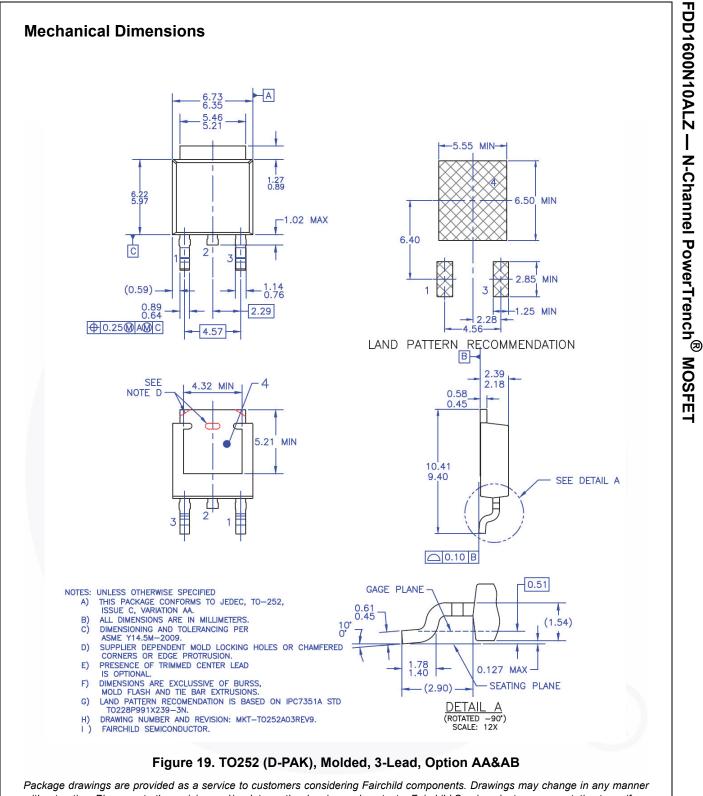






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